

FERD30S50

Field effect rectifier

Datasheet – production data

Features

- CMOS proprietary process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation

Description

This single rectifier is based on a proprietary technology, enabling to achieve the best in class V_F/I_R trade-off for a given silicon surface.

Packaged in PowerFLAT[™] 5x6, this device is intended to be used in rectification and freewheeling operations in switch-mode power supplies.

PowerFLAT 5x6 FERD30S50DJF	

Table 1. Device summary

Symbol	Value
I _{F(AV)}	30 A
V _{RRM}	50 V
T _{j (max)}	+150 °C
V _F (typ)	0.33 V

TM: PowerFLAT is a trademark of STMicroelectronics

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This is information on a product in full production.

1 Characteristics

Table 2. Absolute ratings (limiting values, at 25 °C, unless otherwise specified, anode terminals short-circuited)

Paramete	Value	Unit	
Repetitive peak reverse voltage	50	V	
Forward rms current		45	А
Average forward current, $\delta = 0.5$ $T_c = 95 \text{ °C}$		30	А
Surge non repetitive forward current	180	А	
Storage temperature range	-65 to + 175	°C	
Maximum operating junction temperature	150	°C	
	ParameterRepetitive peak reverse voltageForward rms currentAverage forward current, $\delta = 0.5$ Surge non repetitive forward currentStorage temperature rangeMaximum operating junction temperature	ParameterRepetitive peak reverse voltageForward rms currentAverage forward current, $\delta = 0.5$ $T_c = 95 \ ^{\circ}C$ Surge non repetitive forward current $t_p = 10 \ ms \ sinusoidal$ Storage temperature rangeMaximum operating junction temperature	ParameterValueRepetitive peak reverse voltage50Forward rms current45Average forward current, $\delta = 0.5$ $T_c = 95 \ ^{\circ}C$ 30Surge non repetitive forward current $t_p = 10 \ ms \ sinus \ sinu$

1. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter	Value (max)	Unit
R _{th(j-c)}	Junction to case	2.6	°C/W

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	Reverse leakage current	T _j = 125 °C	V _R = 35 V		25		
$I_R^{(1)}$		T _j = 25 °C	V - V			0.8	mA
		T _j = 125 °C	$v_{R} = v_{RRM}$		30	60	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 5 A		0.32		
		T _j = 125 °C			0.25		
		T _j = 25 °C	I _F = 10 A		0.37		V
		T _j = 125 °C			0.33		v
		T _j = 25 °C	- I _F = 15 A		0.415	0.47	
		T _j = 125 °C			0.39	0.45	

Table 4. Static electrical characteristics (anode terminals short-circuited)

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.205 \text{ x } I_{F(AV)} + 0.017 I_{F}^{2}_{(RMS)}$$



Figure 1. Average forward power dissipation versus average forward current



Figure 3. Relative variation of thermal impedance junction to case versus pulse duration



Figure 5. Junction capacitance versus reverse voltage applied (typical values)

Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$)



Figure 4. Reverse leakage current versus reverse voltage applied (typical values)



Figure 6. Forward voltage drop versus forward current (typical values)





10000

1000

100



Figure 7. Thermal resistance junction to ambient versus copper surface under tab (typical values)

4/8

Doc ID024715 Rev 2



2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.



Figure 8. PowerFLAT-8L dimensions (definitions)

Table 5. PowerFLAT-8L dimensions (values)

			Dimen	sions		
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.80		1.00	0.031		0.039
A1	0.02		0.05	0.001		0.002
A2		0.25			0.010	
b	0.30		0.50	0.012		0.020
D		5.20			0.205	
D2	4.11		4.31	0.162		0.170
е		1.27			0.050	
E		6.15			0.242	
E2	3.50		3.70	0.138		0.146
L	0.50		0.80	0.020		0.031
К	1.275		1.575	0.050		0.062



Doc ID024715 Rev 2



Figure 9. Footprint (dimensions in mm)



3 Ordering information

Table	6.	Ordering	information
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Order code	Marking	Package	Weight	Base qty	Delivery mode
FERD30S50DJF	FD30S50	PowerFLAT 5x6	95 mg	3000	Tape and reel

4 Revision history

Table 7.	Document	revision	historv
1001011	Dooumon	101101011	

Date	Revision	Changes
28-Jun-2013	1	Initial release.
18-Nov-2013	2	Updated <i>Table 1</i> and <i>Table 4</i> . Inserted new <i>Figure 1</i> , <i>Figure 2</i> , <i>Figure 4</i> and <i>Figure 6</i> . Product name changed from FERD30S50DJF to FERD30S50.



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